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# Reduced spin Hall effects from magnetic proximity

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Harnessing spin-orbit coupling for the manipulation of spins and magnetization via electric charge currents is the key objective of spin-orbitronics. Towards this end ferromagnetic materials are combined with non-magnetic materials with strong spin-orbit coupling (typically involving heavy elements). However, many of the nominally non-magnetic materials are highly susceptible to magnetic proximity effects and the role of induced moments for spin transport has been controversial. Here we demonstrate that for Pt and Pd increased induced magnetic moments are correlated with strongly reduced spin Hall conductivities. This observation finds an intuitive explanation in the development of a spin splitting of the chemical potential and the energy dependence of the intrinsic spin Hall effect determined by first-principles calculations. This work provides simple guidance towards the optimization of spin current efficiencies for devices based on spin-orbit coupling phenomena.

## I. INTRODUCTION

The past decade has witnessed the realization that spin-orbit coupling can provide a very efficient pathway for the generation and detection of spin currents. This has given rise to a new paradigm for spintronics, called spin-orbitronics, where the coupling between spin and angular momentum can be used to manipulate magnetizations electrically in metals and insulators<sup>1</sup>. One of the key phenomena is the spin Hall effect (SHE), which converts a charge current to a spin current<sup>2,3</sup>. Conversely, the inverse spin Hall effect (ISHE), transforms a spin current into a charge current<sup>4</sup>. The efficiency of this conversion is characterized by a single material-specific parameter, the spin Hall angle,  $\gamma_{\text{SH}}$ , given by the ratio of spin to charge current<sup>5,6</sup>. Experimentally, the spin Hall angle along with other spin transport properties are often probed via ISHE and injection of a spin current from ferromagnets (FM) to normal metals (NM) with large spin-orbit coupling, using non-local spin valves<sup>7,8</sup>, ferromagnetic resonance (spin pumping)<sup>9-14</sup>, or temperature gradients (spin-Seebeck effect)<sup>15-17</sup>. To maximize the spin Hall signal, the thickness of the NM exceeds in most experiments the spin diffusion length,  $\lambda_{sf}$ , of the NM. However, when a thin NM (thickness below  $\lambda_{sf}$ ) is placed in contact with a FM, interface effects, such as spin-memory loss<sup>12,18</sup> and magnetic proximity effects<sup>19-21</sup> can become pronounced and alter the spin transport properties of the sample. Among the materials studied for large spin Hall effects, Pt and Pd are two of the most popular metals employed, especially Pt, which has been indispensable in the establishment of virtually all the newly discovered pure spin current phenomena<sup>4,5,8-12,15</sup>. At the same time, both Pt and Pd have been well known to order ferromagnetically with even minute amounts of magnetic impurities<sup>22</sup> and give rise to magnetic proximity effects in heterostructures<sup>19-24</sup>. Recently, this started a con-

trovery whether the proximity effects of Pt and Pd are relevant to many magnetotransport characteristics<sup>25-30</sup>. However, if and how they influence the spin Hall effects of Pt and Pd has not been established.

In this work, we experimentally study the temperature evolution of spin Hall effects in Permalloy (Py, Ni<sub>80</sub>Fe<sub>20</sub>)/NM bilayers (NM = Pt or Pd) using spin pumping and ISHE measurements. By focusing on very thin NM, where proximity effects are most pronounced, we observe a significant decrease of the SHE with decreasing temperature. Furthermore, we show how this observation can be quantitatively understood by the energy dependence of the intrinsic spin Hall conductivity determined from first-principles calculations.

## II. EXPERIMENT

We fabricated the devices using our previous recipe<sup>31</sup>. The key samples are thin Pt (0.6 nm) and thin Pd (3 nm) on top of Py layers (15 nm) respectively, deposited by magnetron sputtering at rates less than 1 Å/s. In order to check the interface characteristics of our samples, we first measured x-ray reflectivities and their analysis yields roughness values for all relevant interfaces involved in our samples. For x-ray characterization we grew Py(15 nm)/Pt(10 nm), Py(15 nm)/Pd(10 nm), Py(15 nm)/Cu(4 nm)/Pt(10 nm), and Py(15 nm)/Cu(4 nm)/Pd(10 nm) samples. We found that the roughness is 0.8 nm for both Pt and Pd grown on Py, see Fig. 1 and Table I. In case of Pd, the deposited thickness of the actual sample (3 nm) is greater than the roughness obtained from x-ray study. In case of Pt, the deposited thickness is comparable to the roughness, indicating that the Pt layer may be subject to enhanced surface scattering. However, this surface scattering does not alter the conclusion of our present work, as will be discussed later.

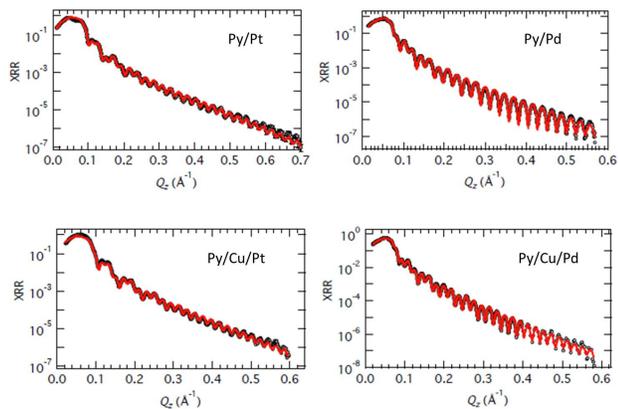


FIG. 1. (Color online) X-ray reflectivity data for Py/Pt(Pd) and Py/Cu/Pt(Pd) samples and the corresponding fittings for determining the roughness values.

The spin pumping samples were patterned in the shape of  $20 \mu\text{m} \times 2 \text{mm}$  stripes using lithography on Si substrates with 300-nm-thick thermally grown  $\text{SiO}_2$ . Electrical leads and a coplanar waveguide (CPW) were subsequently fabricated [Fig. 2(a)]. A 80-nm-thick MgO spacer was used to separate the bilayer stack from the CPW. The measuring frequency was kept between 4 and 6 GHz and the  $rf$  power was 10 mW.

### III. EXPERIMENTAL RESULTS AND DISCUSSIONS

Figure 2(b) and (c) illustrate the  $dc$  voltages measured at 4 GHz for Py/Pt and Py/Pd at selective temperatures. By generating macroscopic spin currents and using an amplitude-modulated lock-in detection, we probe  $dc$  voltages of tens of  $\mu\text{V}$  and obtain clearly distinguishable complex-Lorentzian lineshapes. The signals have superimposed symmetric and antisymmetric Lorentzian components. The antisymmetric component is due to the homodyne anisotropic magnetoresistance (AMR) while the symmetric component originates from the ISHE. Unintentional temperature gradients can give rise to anomalous Nernst voltage with a symmetric component<sup>32</sup>, which we avoid in our samples using a design with a thick high-thermal-conductivity layer above and an even thicker substrate below. The pure AMR-type signal in a pure Py sample<sup>31</sup> demonstrate the absence of both

	Py/Pt	Py/Cu/Pt	Py/Pd	Py/Cu/Pd
Py/ $\text{SiO}_2$	0.34	0.38	0.27	0.33
Cu/Py	n/a	0.76	n/a	0.61
Pt(Pd)/Cu	n/a	0.76	n/a	0.61
Pt(Pd)/Py	0.86	n/a	0.81	n/a
Vac/Pt(Pd)	0.31	0.34	0.44	0.49

TABLE I. Calculated roughness values for each layer of the x-ray samples measured in Fig. 1 (units in nm, Vac = vacuum).

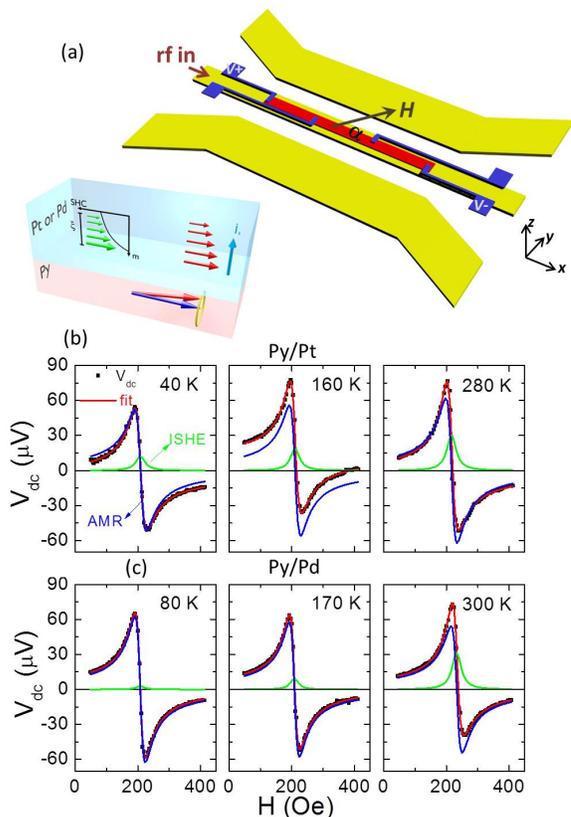


FIG. 2. (Color online) (a) Schematic illustration of the spin pumping and ISHE experiments showing the respective polarity ( $rf$  input, external field,  $H$ , and  $dc$  voltage contacts,  $V_+/V_-$ ), and the external field direction,  $\alpha = 40^\circ$  with respect to the central signal line. Due to magnetic proximity effect, the spin Hall conductivities (SHC) are reduced near the interface, since they are functions of induced magnetic moments that decay away from the interface within a very thin thickness range; these effects are observed by ISHE measurements only for very thin layers of Pt and Pd on top of Py. AMR-ISHE spectra measured at 4 GHz for (b) Py/Pt and (c) Py/Pd at selective temperatures.

anomalous Nernst effect and the self-induced ISHE voltage of Py<sup>33,34</sup>. In Figs. 2(b) and (c), a reduction of the ISHE component with respect to the AMR is observed with decreasing temperature for both Pt and Pd. Since both ISHE and AMR originate from the  $rf$ -driven magnetization precession, both effects have the same  $rf$ -power dependence and the resultant  $dc$  voltage is a sum of the two<sup>31,35</sup>. We define  $W_{\text{ISHE}}$  as the weight of the symmetric component (ISHE), which can be expressed in the form of  $W_{\text{ISHE}} = 1/(1+V_{\text{AMR}}/V_{\text{ISHE}})$ . The ratio of the two components can be written as<sup>31</sup>:

$$\frac{V_{\text{ISHE}}}{V_{\text{AMR}}} = \frac{\gamma_{SH} e L P f g_{\text{mix}} \lambda_{sf}}{R_{\text{CPW}} I_{\text{CPW}}} \frac{h_{rf} \rho_{FM}}{\Delta H t_{FM}} \tanh\left(\frac{t_{NM}}{2\lambda_{sf}}\right), \quad (1)$$

where  $\gamma_{SH}$  is the spin Hall angle,  $L$  is the device length,  $P$  is an ellipticity correction,  $R_{\text{CPW}}$  is the CPW re-

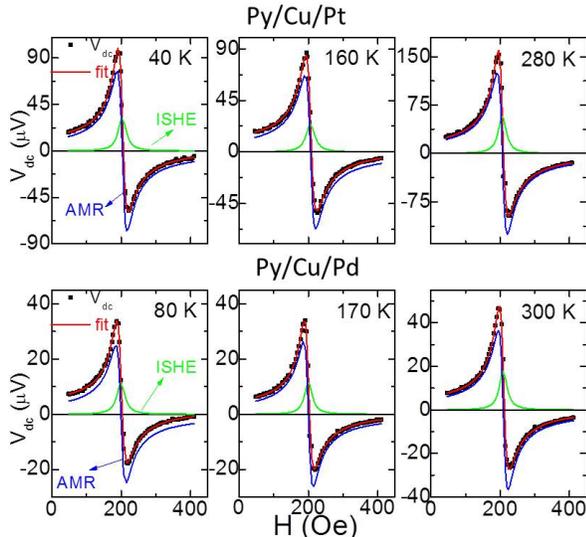


FIG. 3. (Color online) AMR-ISHE spectra measured at 4 GHz for Py/Cu/Pt and Py/Cu/Pd reference samples at selective temperatures.

sistance,  $I_{CPW}$  is the CPW current,  $\frac{\Delta R_{FM}}{R_{FM}}$  is the FM anisotropic magnetoresistance,  $h_{rf}$  is the  $rf$  field,  $\Delta H$  is the linewidth, and  $\rho_{FM}$  is the FM resistivity<sup>31</sup>. In Eq.(1), only the spin Hall angle,  $\gamma_{SH}$ , the spin mixing conductance,  $g_{mix}$ , the spin diffusion length,  $\lambda_{sf}$ , and the normal metal layer thickness,  $t_{NM}$  are dependent on the NM. Therefore,  $W_{ISHE}$  can be re-written as:

$$W_{ISHE} = \left(1 + \frac{1}{C \cdot \gamma_{SH} \cdot g_{mix} \cdot \lambda_{sf} \cdot \tanh\left(\frac{t_{NM}}{2\lambda_{sf}}\right)}\right)^{-1}, \quad (2)$$

where  $C$  depends on  $f$  due to changing  $P$  of the precession<sup>36,37</sup> and is otherwise only a function of the CPW and FM layer.

Figure 3 show the spin pumping data on two reference samples, i.e. Py(15 nm)/Cu(4 nm)/Pt(0.6 nm) and Py(15 nm)/Cu(4 nm)/Pd(3 nm) at selective temperatures. The additional 4 nm Cu spacer in the Py/Cu/NM samples blocks any possible spin interface effects, while it only weakly changes the spin current transport due to the long spin diffusion length of Cu<sup>38</sup>. The symmetric component from ISHE is clearly separated from the asymmetric component that arises from the AMR in the spectrum. No pronounced decay of the ISHE signal is observed for both Pt and Pd. Figure 4 summarize the temperature dependence of  $W_{ISHE}$  values for Pt and Pd with and without a Cu spacer. We note that x-ray reflectivity shows similar roughness for the Pt and Pd layers with and without the Cu interlayer, suggesting that possible changes in microstructure are inconsequential (Fig. 1). In addition,  $W_{ISHE}$  of Py/NM and Py/Cu/NM samples show similar values at room temperature (RT), confirming the weak dependence of spin pumping and ISHE detection on the insertion of the thin Cu layer.

The value of  $W_{ISHE}$  strongly decreases with decreas-

ing temperature in Py/NM samples, while it remains almost temperature independent for Py/Cu/NM samples. The nearly constant  $W_{ISHE}$  for Py/Cu/NM indicates a weak temperature-dependence of the intrinsic SHE ( $\gamma_{SH}$ ,  $g_{mix}$ , and  $\lambda_{sf}$ ) for paramagnetic Pt and Pd, which has also been found using lateral spin valves<sup>39</sup>, spin Hall magnetoresistance<sup>40</sup>, and first-principles calculations<sup>41</sup>. In contrast, we attribute the observed strong temperature dependence in Py/NM bilayers to a temperature-dependent proximity effect of magnetically ordered Pt and Pd. This magnetic proximity arises at the Py/NM interface and reduces the effective spin Hall angle (which is apparent from the decreasing of the ratio  $W_{ISHE}$  with temperature, Fig. 4). Figures 5(a) and (f) show the normalized magnetization versus temperature for extended Py/Pt and Py/Pd samples compared to a Py reference sample. For both Pt and Pd there is an additional net magnetization, which becomes more pronounced at low temperatures. This is consistent with a temperature dependent proximity effect.

Two competing length scales are important in this context: (1) the spin diffusion lengths of the spin current and (2) the correlation length of the proximity effect,  $\xi$ . In our previous studies, we determined the spin diffusion length of Pt (1.2 nm)<sup>31</sup> and Pd (5.5 nm)<sup>35</sup>, which is nearly a temperature-independent parameter<sup>31,40</sup>. However, in these studies we investigated thicker layers ( $t_{NM} > 1$  nm) and it was shown that  $W_{ISHE}$  for Pt is almost the same at RT and 10 K. These results imply that the correlation length is on the order of less than 1 nm for Pt at 10 K, and less than 3 nm for Pd from our present work. Strong temperature-dependent  $\xi$  has been

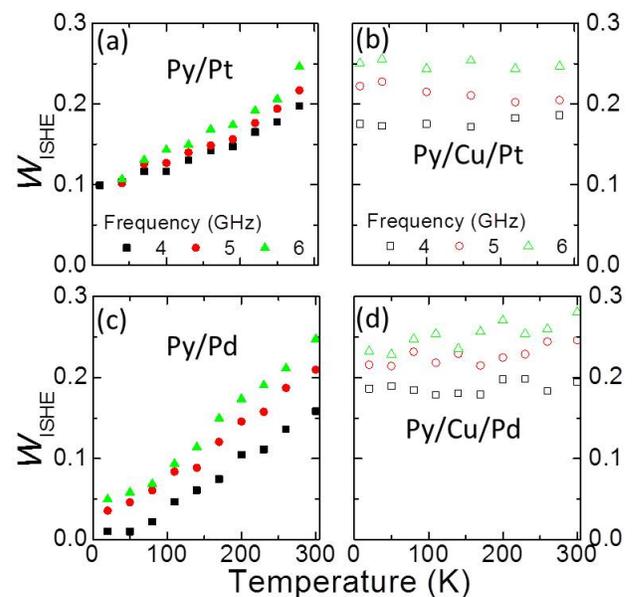


FIG. 4. (Color online) Temperature dependence of  $W_{ISHE}$  at 4, 5, and 6 GHz for (a) Py/Pt, (b) Py/Cu/Pt, (c) Py/Pd, and (d) Py/Cu/Pd bilayers.

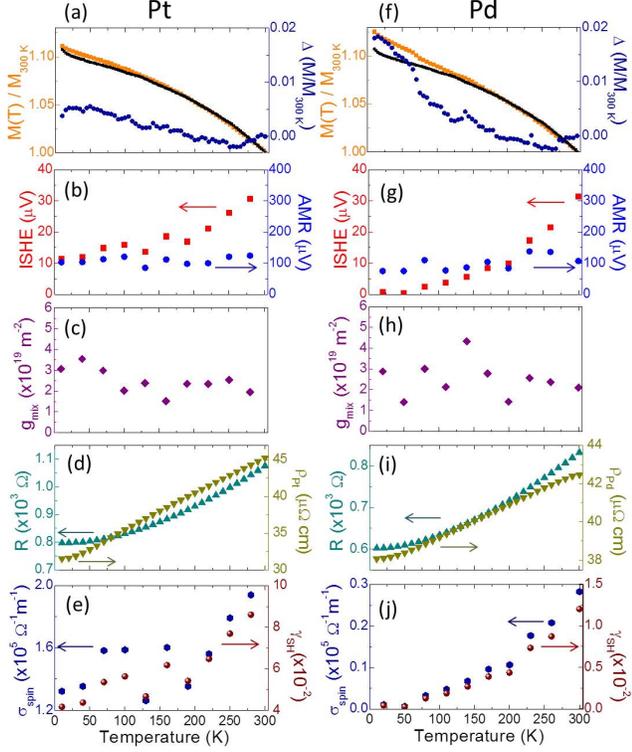


FIG. 5. (Color online) Temperature dependence of (a) normalized magnetization,  $M(T)/M_{300\text{K}}$  (with respect to 300 K) of Py/Pt and Py and their differences ( $\Delta$ ), measured by a SQUID magnetometry with 2k Oe in-plane applied field. (b) AMR and ISHE voltage amplitudes at 4 GHz, (c) spin mixing conductance, (d) device total resistance and Pt resistivity, and (e) calculated spin Hall angle and spin Hall conductivity for Pt. Right panel (f)-(j) are corresponding results for Pd.

reported in Py/Pt<sup>28</sup>, YIG/Pt<sup>42</sup> and YIG/Pd<sup>29,43</sup>, with  $\xi \sim 0.8$  nm for Pt<sup>28</sup> and  $\xi \sim 2$  nm for Pd<sup>29</sup> at low temperatures. We suggest that the observed reduction of the SHE in thin Pt and Pd is due to a temperature-dependent magnetic proximity effect obvious from a strong variation of the ratio  $\xi/\lambda_{sf}$  with temperature.

In order to quantify the temperature-dependent spin Hall angle of the thin Pt and Pd, we distinguish the absolute values of the two voltage components. Figure 5(b) and (g) show the temperature dependence of ISHE and AMR voltages obtained at 4 GHz for Pt and Pd respectively, which confirm that the decreasing  $W_{\text{ISHE}}$  is purely due to the decreased ISHE. We also extract the effective spin mixing conductance from the damping enhancement due to spin pumping,  $\Delta\alpha$  [Fig. 2(b) and (c)], according to<sup>9,12,35</sup>:

$$g_{\text{mix}} = \frac{4\pi M_s t_{FM}}{g\mu_B} \Delta\alpha, \quad (3)$$

where  $g$ ,  $\mu_B$ , and  $M_s$  are the Landé  $g$  factor, Bohr magneton, and saturation magnetization of Py, respectively. We do not observe any appreciable temperature depen-

dence of  $g_{\text{mix}}$  [Fig. 5(c) and (h)]. The spin Hall angle can be estimated via<sup>9,35</sup>:

$$V_{\text{ISHE}} = R\gamma_{SH}ewPf g_{\text{mix}} \sin\alpha \sin^2\theta \lambda_{sf} \tanh\left(\frac{t_{NM}}{2\lambda_{sf}}\right), \quad (4)$$

where  $w$  is the stripe-width and  $R$  is the total bilayer resistance, which is directly measured, see Fig. 5(d) and (i). Using these values, the spin Hall angles at different temperatures are estimated [Fig. 5(e) and (j)] by assuming a temperature-independent precession cone-angle,  $\theta$ ,  $g_{\text{mix}}$ , and  $\lambda_{sf}$ . For Pt, the spin Hall angle decreases from 0.086 at RT<sup>31</sup> to 0.042 at 10 K, i.e., more than a factor of 2; for Pd, we found nearly negligible SHE at low temperatures as compared to a spin Hall angle at RT of 0.012<sup>35</sup>. This result indicates a more pronounced proximity effect for Pd than for Pt. We also calculate the temperature-dependent SHE conductivity  $\sigma_{\text{spin}}$  from the relation  $\gamma_{SH} = \sigma_{\text{spin}}/\sigma$ , where  $\sigma$  is the electrical conductivity of NMs,  $\sigma = \rho^{-1}$ . Furthermore, we estimate the resistivity of thin Pt and Pd layers from independent samples (2-nm Pt and 3-nm Pd) using four-point measurements. For Pt, the SHE conductivity reduces from  $(1.9 \pm 0.2) \times 10^5 \Omega^{-1}\text{m}^{-1}$  at RT to  $(1.3 \pm 0.2) \times 10^5 \Omega^{-1}\text{m}^{-1}$  at 10 K; for Pd, it is  $(0.3 \pm 0.1) \times 10^5 \Omega^{-1}\text{m}^{-1}$  and almost negligible (below our detection limit) at  $T < 80$  K. It is noted that our samples may be subjected to enhanced surface scattering due to the thin layers of Pt and Pd, however, such fact would not alter our conclusion. On one hand, it is the total device resistance, instead of the independently characterized resistivity that dictates the measured spin Hall voltages [Eq. (4)]. On the other hand, this surface scattering would only increase the resistivity of Pt, and also makes its temperature-dependence less significant. Therefore, the spin Hall conductivity values at lower temperatures may be overestimated in our case, implying an even stronger reduction of spin Hall effects due to the magnetic proximity effect. Finally, we found that the roughnesses for Pt and Pd grown on Cu show comparable but slightly reduced values (Fig. 1), indicating a smoother interface between Cu and Pt (Pd).

#### IV. FIRST-PRINCIPLES CALCULATIONS

In order to assess the influence of the proximity induced moment, we calculated the SHE conductivity of magnetized bulk fcc Pt and Pd from first principles. We determined the electronic structure of paramagnetic Pt and Pd within the generalized gradient approximation (GGA) to density functional theory<sup>44</sup>. The calculations were performed with the full-potential linearized augmented-plane-wave code FLEUR<sup>45</sup>. In order to minimize the computational cost, we made use of Wannier interpolation<sup>46</sup>. We constructed 18 maximally localized Wannier functions<sup>47,48</sup> per atom describing the 5s, 4d and 5p states in Pd and the 6s, 5d and 6p states in Pt. Using the electronic structure of the paramagnetic bulk

elements represented in the Wannier function basis, we evaluated the intrinsic SHE conductivity

$$\sigma_{\text{spin}}(E) = \frac{-4e^2}{N} \sum_{\mathbf{k}} \sum_{\epsilon_{\mathbf{k}n} < E < \epsilon_{\mathbf{k}m}} \text{Im} \frac{\langle \mathbf{k}n | Q_x^z | \mathbf{k}m \rangle \langle \mathbf{k}m | v_y | \mathbf{k}n \rangle}{(\epsilon_{\mathbf{k}n} - \epsilon_{\mathbf{k}m})^2} \quad (5)$$

as a function of chemical potential  $E$ . Here,  $N$  is the number of  $k$ -points  $\mathbf{k}$ ,  $\epsilon_{\mathbf{k}n}$  is the band energy,  $v_y$  is the  $y$  component of velocity and  $Q_x^z = \frac{\hbar}{4V} [\sigma_z v_x + v_x \sigma_z]$  is the spin current density with  $V$  the unit cell volume and  $\sigma_z$  a Pauli matrix. A  $800 \times 800 \times 800$  Monkhorst-Pack  $k$ -mesh<sup>49</sup> was employed to sample the Brillouin zone. The SHE conductivity with a proximity induced spin magnetic moment  $\mu$  is estimated as  $\sigma_{\text{spin}} = [\sigma_{\text{spin}}(E_{\uparrow}) + \sigma_{\text{spin}}(E_{\downarrow})]/2$ , where  $E_{\uparrow}$  and  $E_{\downarrow}$  are determined from  $\mu = n(E_{\downarrow}) - n(E_{\uparrow})$  and  $2n(E_F) = n(E_{\uparrow}) + n(E_{\downarrow})$ , where  $2n(E)$  is the number of states with energy lower than  $E$  in the paramagnetic system, and  $2n(E_F) = 10$  is the number of valence electrons. In Fig.6 (a) and (b) we show the SHE conductivity as a function of chemical potential for the paramagnetic case. In the case of Pt, a pronounced maximum is located at  $E = E_F$ . The chemical potential dependence in Pd is very similar to the Pt case but the maximum is shifted to roughly 0.3 eV below  $E_F$ . Since both Pt and Pd have their Fermi level close to the maximum

of the SHE conductivity, spin dependent changes of the band structure, which are akin to a spin-splitting of the chemical potential upon the development of a net magnetic moment, lead to a reduction of SHEs.

Figure 6(c) and (d) show the calculated SHE conductivity in the presence of an induced spin magnetic moment. Due to the maximum of the SHE conductivity at  $E = E_F$  for Pt, the SHE conductivity decreases significantly with increasing moment  $\mu$  in Fig. 6(c). In contrast, the induced-moment dependence of the SHE in Pd shown in Fig.6(d) is much weaker because the maximum of the SHE conductivity in Fig.6(b) is shifted to 0.3 eV below  $E_F$ . In the absence of a spin magnetic moment in Pt we obtain  $\sigma_{\text{spin}} = 4.37 \times 10^5 \Omega^{-1} \text{m}^{-1}$ , which compares satisfactorily with  $\sigma_{\text{spin}} = 1.9 \times 10^5 \Omega^{-1} \text{m}^{-1}$  measured experimentally at RT. However, the experimental RT value of  $\sigma_{\text{spin}} = 0.3 \times 10^5 \Omega^{-1} \text{m}^{-1}$  in Pd is considerably smaller than the theoretical value of  $\sigma_{\text{spin}} = 2.1 \times 10^5 \Omega^{-1} \text{m}^{-1}$  at  $\mu = 0$ . The relatively large difference in the case of Pd might result from shortcomings of the electronic structure obtained from the GGA<sup>50</sup>. Furthermore, additional extrinsic mechanisms might contribute to SHE, and reduce the SHE angle if they are opposite to the intrinsic mechanism considered here. Experimentally the SHE conductivity in Pt reduces by 32% from RT to 20 K, which can be explained theoretically by an increase of the induced Pt moment by  $0.5 \mu_B$  [see Fig. 6(c)]. This is similar to values found with elements specific x-ray magnetic dichroism measurements finding values of induced Pt moment per atom to be  $0.1 - 0.3 \mu_B$  in Ni/Pt<sup>20</sup> and  $0.7 \mu_B$  in Co/Pt<sup>23</sup>, and  $0.5 \mu_B$  in Fe/Pt<sup>24</sup>. In addition, through thickness studies, such a proximity induced magnetization is found to be maintained for Pt thickness up to 1 nm. Thus for Pt this simple picture with a temperature dependent proximity-induced magnetization explains quantitatively the observed reduction of the SHE.

On the other hand, the situation in Pd appears to be more complex. The theoretical reduction of the SHE in Pd by an induced moment as shown in Fig. 6(d) underestimates the relative reduction seen in experiment. As discussed above we may not sufficiently accurately capture the electronic structure within the GGA. An alternative explanation is the presence of an additional external SHE contribution of opposite sign. Interestingly, the absolute change of SHE between RT and 20 K of  $0.3 \times 10^5 \Omega^{-1} \text{m}^{-1}$  does compare to the absolute reduction by  $0.29 \times 10^5 \Omega^{-1} \text{m}^{-1}$  between  $\mu = 0$  and  $\mu = 0.5 \mu_B$  [see Fig. 6(d)] suggesting that a temperature-independent offset by  $1.8 \times 10^5 \Omega^{-1} \text{m}^{-1}$  due to an additional extrinsic mechanism might explain the discrepancy between experiment and theory.

## V. CONCLUSIONS

In summary, we showed the temperature-dependent spin pumping and inverse spin Hall effects in thin Pt

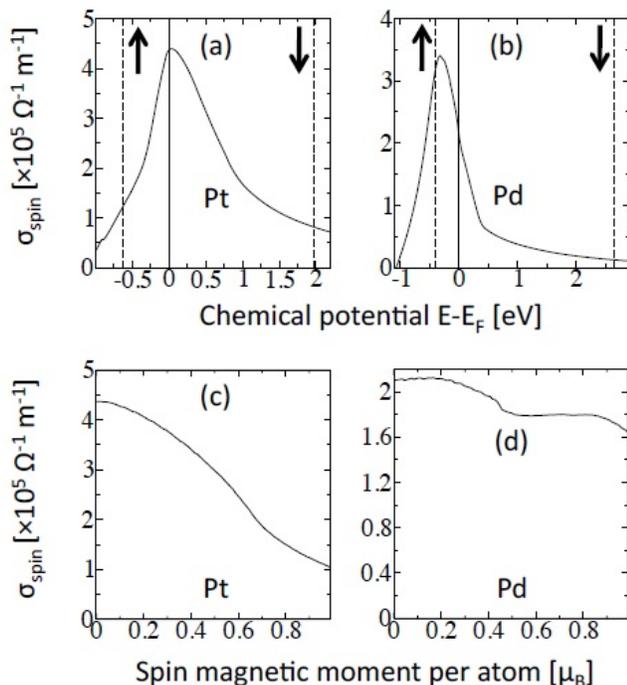


FIG. 6. (a) and (b): Chemical potential dependence of the intrinsic SHE conductivity in Pt and Pd. The dashed lines indicate the spin Hall conductivities  $\sigma_{\text{spin}}(E_{\downarrow})$  of the majority spins and  $\sigma_{\text{spin}}(E_{\uparrow})$  of the minority spins in a spin polarized system with an induced moment of  $1 \mu_B$ . (c) and (d): Estimated dependence of the intrinsic SHE conductivity on the proximity induced spin magnetic moment.

and Pd layers in direct contact with Py. We observe a pronounced decrease of the spin Hall effect with decreasing temperature, which is attributed to a temperature-dependent proximity effect. By first-principles calculations, we show that the spin Hall conductivity reduces by increasing the proximity-induced spin magnetic moments. While the experimental observation for Pt is quantitatively consistent with the theoretical calculations, the results for Pd may require additional investigations for their detailed understanding. Nevertheless, the straightforward explanation of the induced moment dependence of the spin Hall effect by a spin splitting of the chemical potential together with the energy dependence of the spin Hall conductivity provides a general pathway for estimating the influence of proximity effects in arbitrary materials. Therefore this will help designing

magnetic multilayers for maximum spin current efficiency in spin-orbitronics device concepts.

## VI. ACKNOWLEDGMENTS

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